



POWER SKY (H.K.) LTD.

TO-220 Plastic-Encapsulate Transistors

TIP120,121,122 Darlington TRANSISTOR (NPN)

TIP125,126,127 Darlington TRANSISTOR (PNP)

TO-220

1.BASE

2.COLLECTOR

3.EMITTER

1 2 3

FEATURES

Medium Power Complementary silicon transistors

MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	TIP120 TIP125	TIP121 TIP126	TIP122 TIP127	Units
V_{CBO}	Collector-Base Voltage	60	80	100	V
V_{CEO}	Collector-Emitter Voltage	60	80	100	V
V_{EBO}	Emitter-Base Voltage	5			V
I_C	Collector Current -Continuous	5			A
P_C	Collector Power Dissipation	2			W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient	62.5			$^\circ\text{C}/\text{W}$
$R_{\theta Jc}$	Thermal Resistance Junction to Case	1.92			$^\circ\text{C}/\text{W}$
T_J	Junction Temperature	150			$^\circ\text{C}$
T_{stg}	Storage Temperature	-55to+150			$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_{amb}=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage TIP120,TIP125 TIP121,TIP126 TIP122,TIP127	$V(BR)_{CBO}$	$I_C=1\text{mA}, I_E=0$	60 80 100		V
Collector-emitter breakdown voltage TIP120,TIP125 TIP121,TIP126 TIP122,TIP127	$V_{CEO(SUS)}$	$I_C=30\text{mA}, I_B=0$	60 80 100		V
Collector cut-off current TIP120,TIP125 TIP121,TIP126 TIP122,TIP127	I_{CBO}	$V_{CB}=60\text{V}, I_E=0$ $V_{CB}=80\text{V}, I_E=0$ $V_{CB}=100\text{V}, I_E=0$		0.2	mA
Collector cut-off current TIP120,TIP125 TIP121,TIP126 TIP122,TIP127	I_{CEO}	$V_{CE}=30\text{V}, I_B=0$ $V_{CE}=40\text{V}, I_B=0$ $V_{CE}=50\text{V}, I_B=0$		0.5	mA
Emitter cut-off current	I_{EBO}	$V_{EB}=5\text{V}, I_C=0$		2	mA
DC current gain	$h_{FE(1)}$	$V_{CE}=3\text{V}, I_C=0.5\text{A}$	1000		
	$h_{FE(2)}$	$V_{CE}=3\text{V}, I_C=3\text{A}$	1000		
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=3\text{A}, I_B=12\text{mA}$ $I_C=5\text{A}, I_B=20\text{mA}$		2 4	V
Base-emitter voltage	V_{BE}	$V_{CE}=3\text{V}, I_C=3\text{A}$		2.5	V
Output Capacitance TIP125,TIP126,TIP127 TIP120,TIP121,TIP122	C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=0.1\text{MHz}$		300 200	pF

Typical Characteristics

TIP120,121,122,125,126,127

